



SMD Type Photo Diode with Daylight Filter

Features

- Small double-end package
- High sensitivity
- High reliability
- Spectral range of sensitivity: 700-1100nm
- Fast Response time
- RoHS compliance

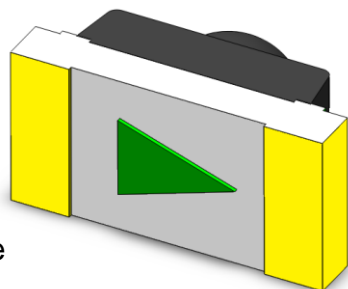
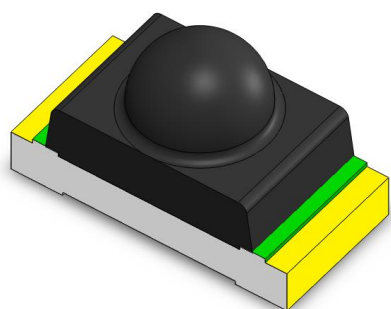
Applications

- Infrared sensor

Description

The PDP91608BT09 is a silicon photo diode housed in a miniature SMD package. The device comes with a superior filtering for visible light by utilizing special black molding compound.

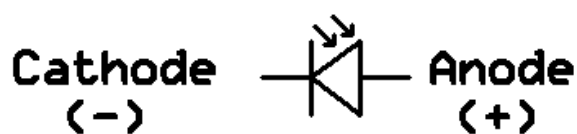
Package Outline



Anode

Cathode

Schematic





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Absolute Maximum Rating at 25°C

| Symbol | Parameters | Ratings | Units | Notes |
|------------------|-------------------------|------------|-------|-------|
| V _R | Reverse Voltage | 33 | V | |
| T _{opr} | Operating Temperature | -40 ~ +85 | °C | |
| T _{stg} | Storage Temperature | -40 ~ +100 | °C | |
| T _{sol} | Soldering Temperature | 260 | °C | 1 |
| P _{to} | Total Power Dissipation | 150 | mW | |

Electro-Optical Characteristics *TA = 25°C (unless otherwise specified)*

Optical Characteristics

| Symbol | Parameters | Test Conditions | Min | Typ | Max | Units | Notes |
|------------------|--------------------|--------------------|-----|-----|------|-------|-------|
| λ | Spectral Bandwidth | - | 700 | - | 1100 | nm | |
| λ _P | Peak Sensitivity | - | - | 900 | - | nm | |
| θ _{1/2} | View Angle | V _R =5V | - | ±45 | - | deg | |

Electrical Characteristics

| Symbol | Parameters | Test Conditions | Min | Typ | Max | Units | Notes |
|-----------------|---------------------------|---|-----|------|-----|-------|-------|
| I _D | Dark Current | E _e =0mW /cm ² V _R =10V | - | - | 10 | nA | |
| V _{BR} | Reverse Breakdown Voltage | E _e =0mW /cm ² I _R =100μA | 33 | - | - | V | |
| V _{OC} | Open-Circuit Voltage | E _e =1mW /cm ² | - | 0.30 | - | V | |
| I _{SC} | Short-Circuit Current | λ _P =940nm | - | 0.95 | - | μA | |
| I _{RL} | Reverse Light Current | E _e =1mW /cm ² λ _P =940nm, V _R =5V | 0.5 | 1.15 | - | μA | |
| C _T | Transition Capacitance | E _e =0mW /cm ² f=1MHz, V _R =5V | - | 0.85 | - | pF | |



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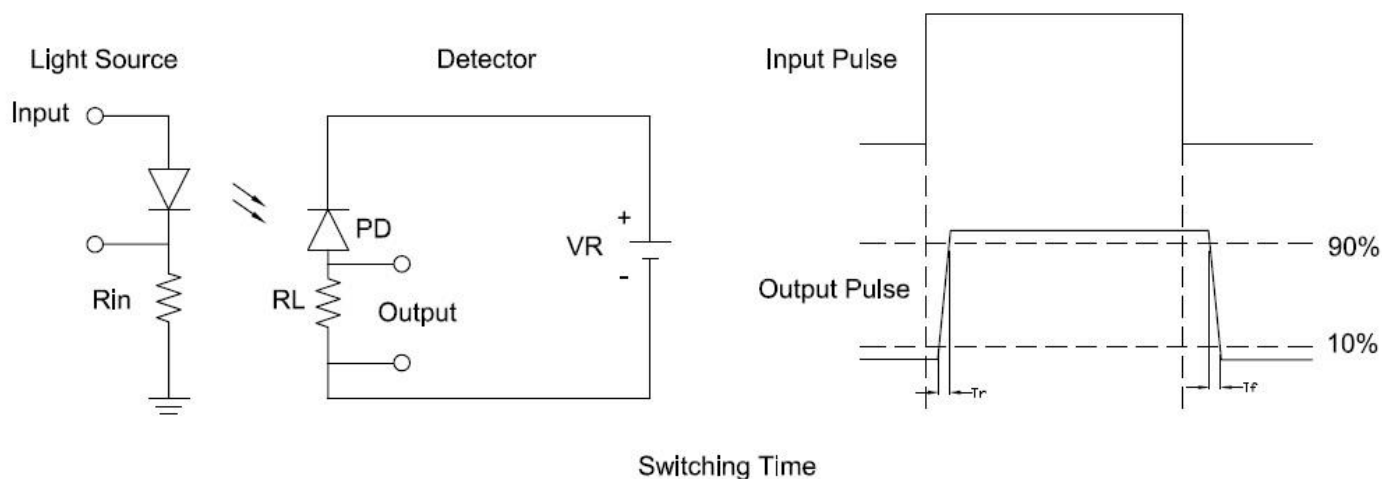
Switching Characteristics

| Symbol | Parameters | Test Conditions | Min | Typ | Max | Units | Notes |
|--------|------------|------------------------------|-----|-----|-----|-------|-------|
| t_r | Rise Time | $V_R = 10V, R_L = 10k\Omega$ | - | 230 | - | ns | 2 |
| t_f | Fall Time | | - | 200 | - | | |

Notes:

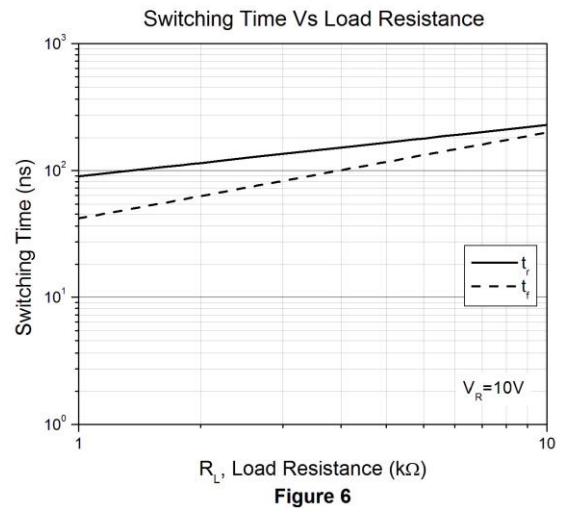
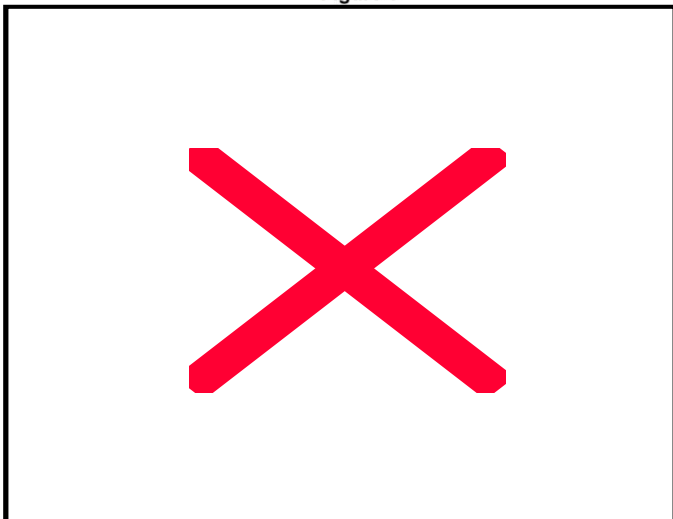
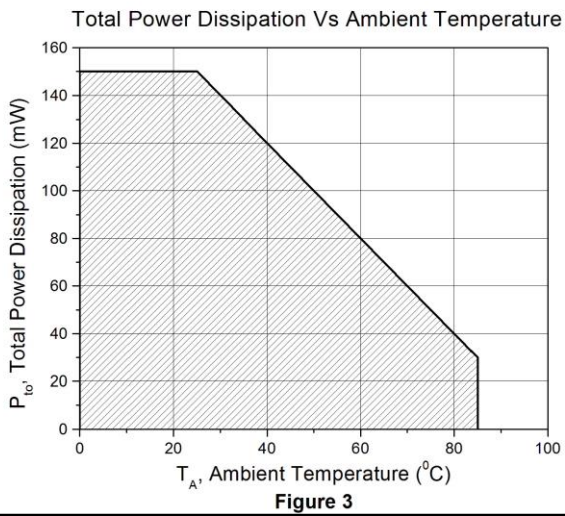
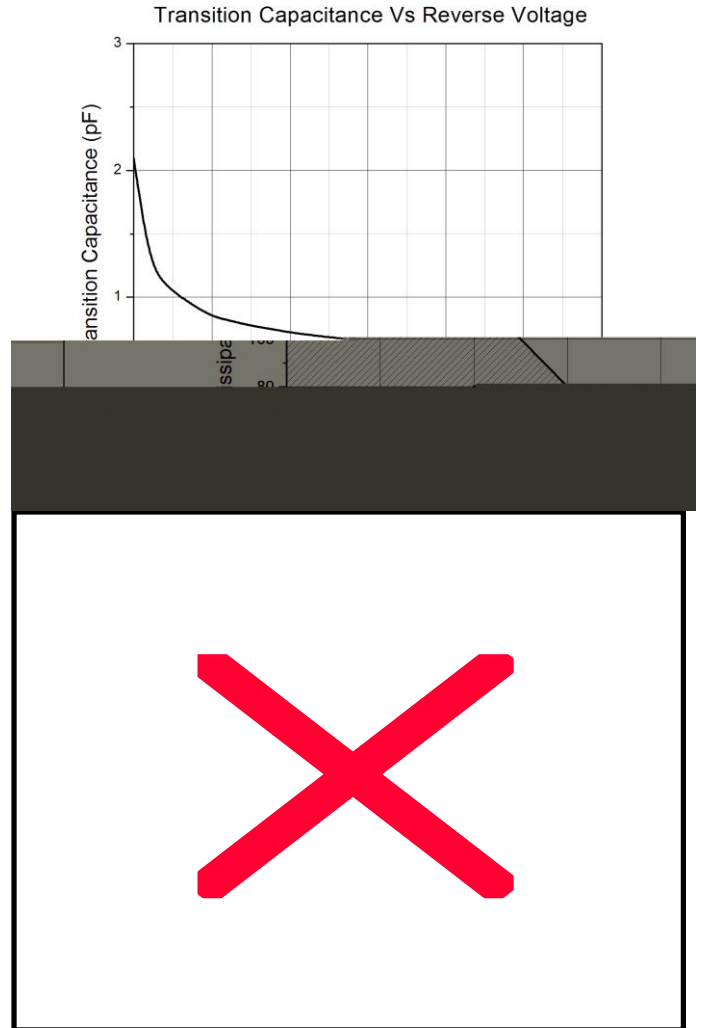
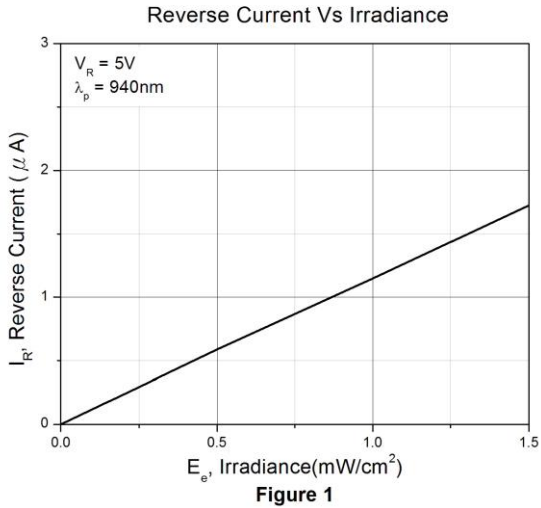
1 : Soldering time ≤ 5 seconds.

2 : Test circuit :





Typical Characteristic Curves





Typical Characteristic Curves

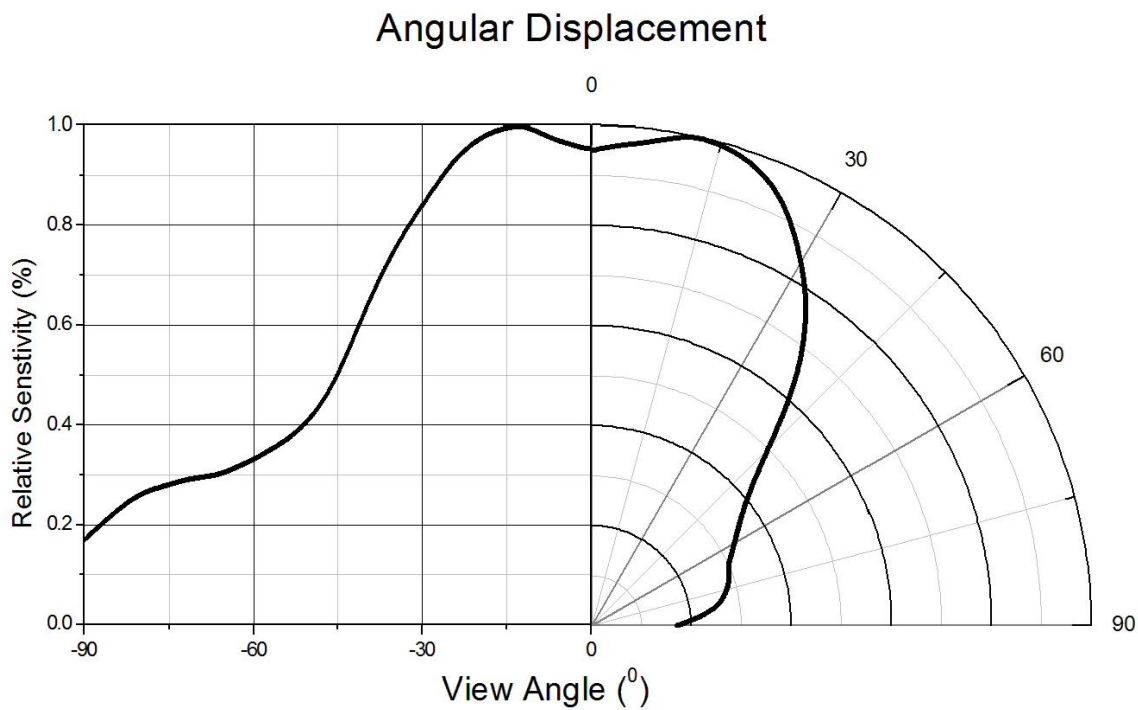
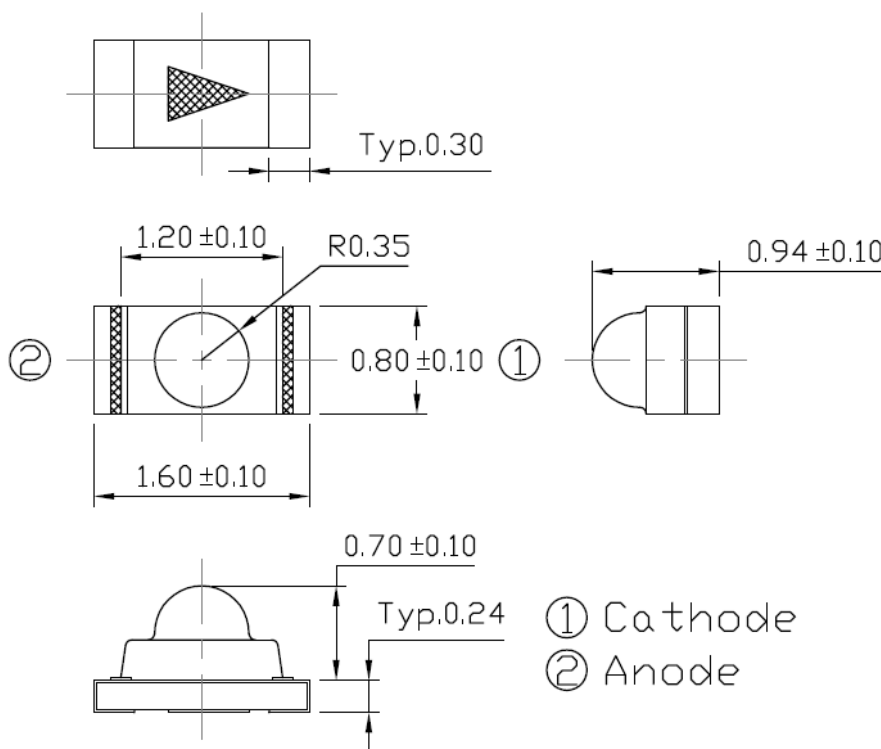


Figure 7

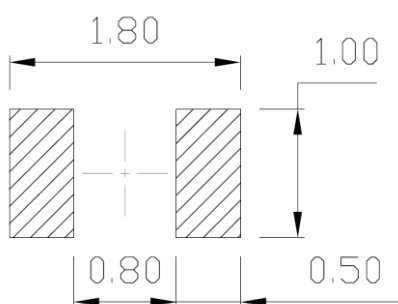


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Package Dimension *All dimensions are in mm, unless otherwise stated*



Recommended Soldering Mask *All dimensions are in mm, unless otherwise stated*



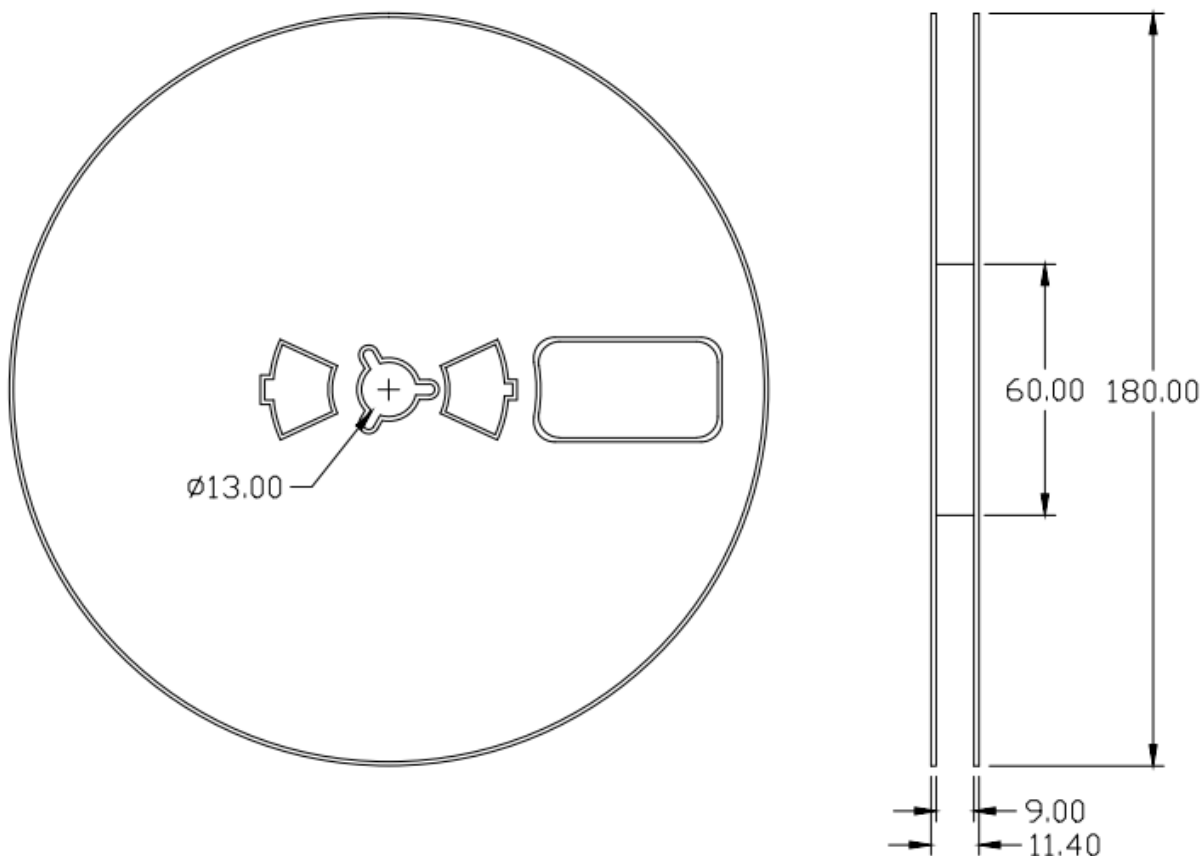
Ordering Information

| Part Number | Description | Quantity |
|--------------|-------------|----------|
| PDP91608BT09 | Tape & Reel | 4000 pcs |

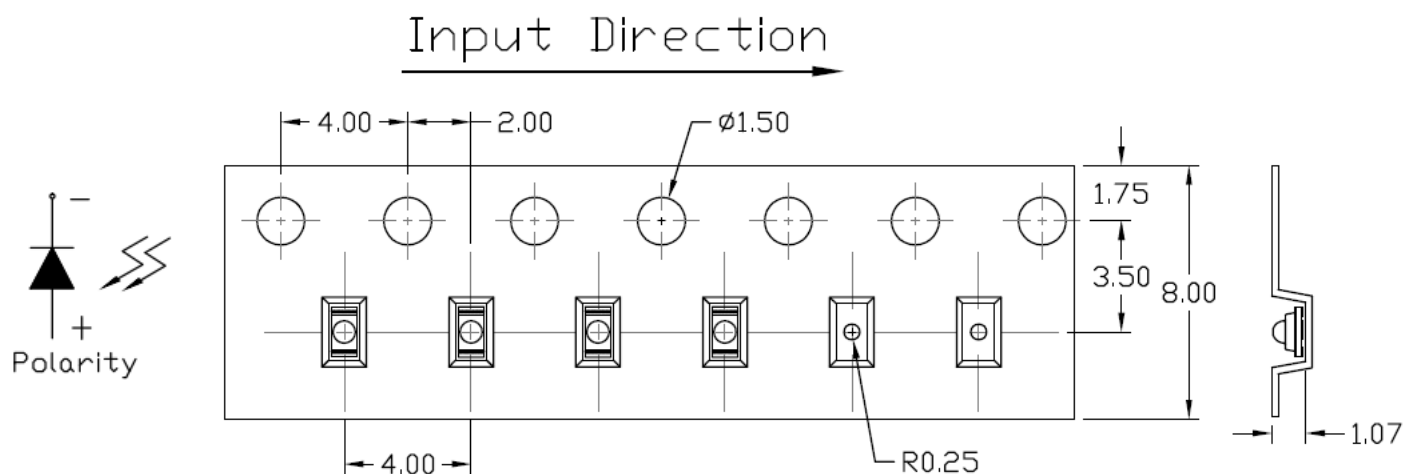


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Reel Dimension *All dimensions are in mm, unless otherwise stated*



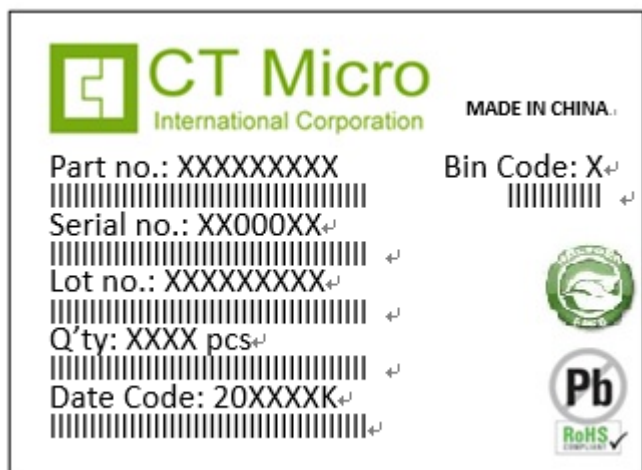
Tape Dimension *All dimensions are in mm, unless otherwise stated*





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Label Form Specification



Part no: CTM Production Number
 Serial no: Production Number
 Lot no: Lot number
 Q'ty: Packing Quantity
 Date Code: Manufacture Date
 Bin Code: IRL Ranks
 MADE IN CHINA: Production Place

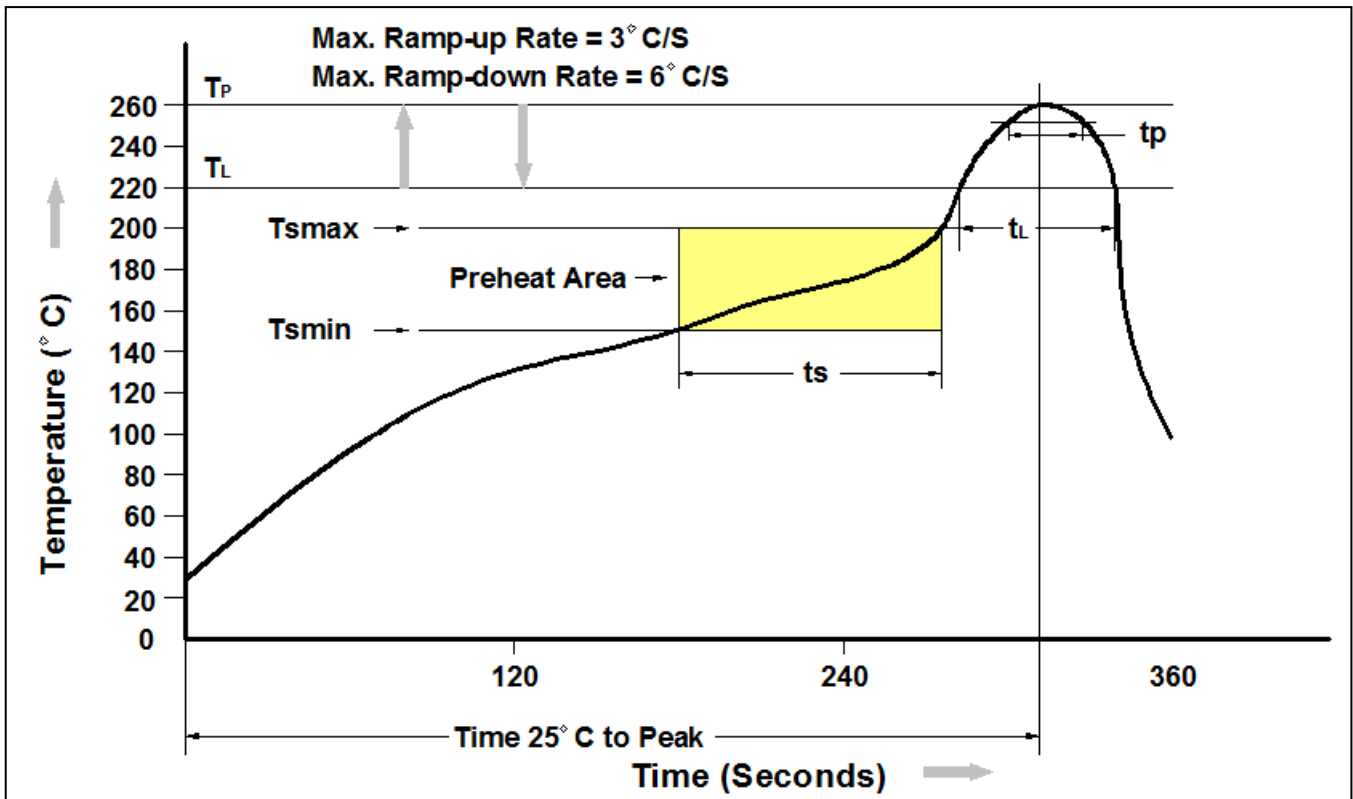
Storage Condition

1. Do not open moisture proof bag before the products are ready to use.
2. The moisture barrier bag should be stored at 30°C and 90%R.H. max. before opening.
Shelf life of non-opened bag is 12 months after the bag sealing date.
3. After opening the moisture barrier bag floor life is 168h at 30°C/60%RH. max. Unused LEDs should be resealed into moisture barrier bag. (Refer to J-STD-020 Standard)
4. If the moisture absorbent material has faded away or the LEDs have exceeded the storage time, baking treatment should be performed using the J-STD-033 Standard conditions.



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Reflow Profile



| Profile Feature | Pb-Free Assembly Profile |
|---|--------------------------|
| Temperature Min. (T _{sm}) | 150°C |
| Temperature Max. (T _{sm}) | 200°C |
| Time (t _s) from (T _{sm} to T _{sm}) | 60-120 seconds |
| Ramp-up Rate (t _L to t _P) | 3°C/second max. |
| Liquidous Temperature (T _L) | 217°C |
| Time (t _L) Maintained Above (T _L) | 60 – 150 seconds |
| Peak Body Package Temperature | 260°C +0°C / -5°C |
| Time (t _P) within 5°C of 260°C | 30 seconds |
| Ramp-down Rate (T _P to T _L) | 6°C/second max |
| Time 25°C to Peak Temperature | 8 minutes max. |



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